

S/N: 10/718,789

5/14/2007

Docket No.: **SUG-176-USAP**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Serial No.: 10/718,789

Confirmation No.: 1591

Applicant: Kazunori HAGIMOTO et al.

Art Unit: 2814

Filed: November 24, 2003

Examiner: Howard Weiss

Docket No: SUG-176-USAP

Customer No: 28892

For: **Light-Emitting Device, Method of Fabricating the Same, and OHMIC Electrode Structure for Semiconductor Device**

**INFORMATION DISCLOSURE STATEMENT**  
**PURSUANT TO 37 C.F.R. §§ 1.56, 1.97, and 1.98**

US Patent & Trademark Office  
Customer Service Window  
Randolph Building  
401 Dulany Street  
Alexandria, VA 22314

Sir:

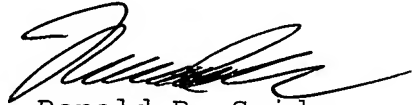
In compliance with the dictates of 37 C.F.R. §§ 1.56, 1.97, and 1.98, Applicant hereby submits an Information Disclosure Statement.

Applicant hereby reports the issuance of an Office Action in the corresponding Japanese application. A copy of the references together with PTO Form 1449 listing each of the references is attached hereto. In accordance with MPEP § 609 III A(2), copies of US patent documents are not attached for applications filed after June 30, 2003 (MPEP Rev. 2, May 2004, page 600-128).

It is respectfully requested that the Examiner consider each of these references and indicate such consideration by enclosing an appropriately initialled copy of the enclosed form PTO-1449 with the next communication from the Patent Office.

INFORMATION DISCLOSURE STATEMENT TRANSMITTAL - PAGE 2 OF 2

Respectfully submitted,

A handwritten signature in black ink, appearing to read 'R. Snider', is written over the typed name.

Ronald R. Snider  
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Date: May 14, 2007

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## INFORMATION DISCLOSURE STATEMENT - PTO FORM 1449

U.S. PATENT DOCUMENTS			
Examiner Initials*	U.S. Patent Document Number	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
	5,917,202 (JP 9-186365)	Haitz et al.	06-29-1999

FOREIGN PATENT DOCUMENTS				
Examiner Initials*	Foreign Patent Document Number	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	T**
	JP 2001-7389 (w/ Eng. Abstract)	Tokyo Shibaura Electric Co.	01-12-2001	
	JP 9-186365 (w/ Eng. Abstract) (5,917,202)	Hewlett Packard Co.	07-15-1997	
	JP 5-251739 (w/ Eng. Abstract)	Tokyo Shibaura Electric Co.	09-28-1993	

Examiner Signature		Date Considered	
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\***Examiner:** Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

\*\*Applicant is to place a check mark here if English language translation is attached